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## Vishay General Semiconductor

# **Dual Low-Voltage Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.34 \text{ V}$  at  $I_F = 5.0 \text{ A}$ 

## TMBS<sup>®</sup> eSMP<sup>®</sup> Series SMPD (TO-263AC)



HEATSINK

PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 10 A			
$V_{RRM}$	45 V			
I <sub>FSM</sub>	120 A			
$V_F$ at $I_F = 10$ A $(T_A = 125  ^{\circ}C)$	0.40 V			
T <sub>J</sub> max.	150 °C			
Package	SMPD (TO-263AC)			
Diode variation	Common cathode			

#### **FEATURES**

- Trench MOS Schottky technology
- Very low profile typical height of 1.7 mm
- · Ideal for automated placement
- · Low forward voltage drop, low power losses
- · High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available:
  - Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912"><u>www.vishav.com/doc?99912</u></a>

### TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection in commercial, industrial, and automotive application.

#### **MECHANICAL DATA**

Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant

Base P/NHM3 - halogen-free, RoHS-compliant, and

AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 and HM3 suffix meet JESD 201 class 2 whisker test

Polarity: As marked

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	V20D45C	UNIT	
Device marking code			V20D45C		
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	45	V	
Maximum average forward rectified current (fig. 1)	per device	I <sub>F(AV)</sub> (1)	20	Λ	
	per diode		10	Α	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load		I <sub>FSM</sub>	120	А	
Operating junction temperature range		T <sub>J</sub> <sup>(2)</sup>	-40 to +150	°C	
Storage temperature range		T <sub>STG</sub>	-55 to +150		

#### Notes

<sup>(1)</sup> Mounted on infinite heatsink

 $<sup>^{(2)}</sup>$  The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta,JA}$ 



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I <sub>F</sub> = 5 A	T <sub>A</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.44	-	V
	I <sub>F</sub> = 10 A			0.49	0.57	
	I <sub>F</sub> = 5 A	T <sub>A</sub> = 125 °C		0.34	-	
	I <sub>F</sub> = 10 A			0.40	0.50	
Reverse current at rated V <sub>R</sub> per diode	V <sub>R</sub> = 45 V	T <sub>A</sub> = 25 °C T <sub>A</sub> = 125 °C	I <sub>R</sub> <sup>(2)</sup>	-	1	- mA
	v <sub>R</sub> = 45 v	T <sub>A</sub> = 125 °C		10	20	
Typical junction capacitance	4.0 V, 1 MHz		CJ	1900	-	pF

#### **Notes**

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width  $\leq 5 \text{ ms}$ 

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	V20D45C	UNIT	
Typical thermal resistance ner device	R <sub>0</sub> JC <sup>(1)</sup>	1.8	°C/W	
Typical thermal resistance per device	R <sub>0</sub> JA (2)(3)	48	C/VV	

#### **Notes**

- (1) Mounted on infinite heatsink
- $^{(2)}$  The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta JA}$
- (3) Free air, without heatsink

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
V20D45C-M3/I	0.55	I	2000/reel	13" diameter plastic tape and reel		
V20D45CHM3/I (1)	0.55	I	2000/reel	13" diameter plastic tape and reel		

#### Note

(1) AEC-Q101 qualified

### RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

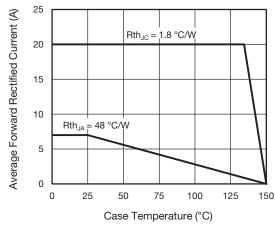


Fig. 1 - Maximum Forward Current Derating Curve

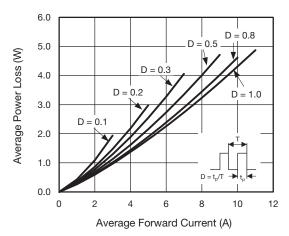


Fig. 2 - Average Power Loss Characteristics



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#### 100 Instantaneous Forward Current (A) 10 T<sub>1</sub> = 125 °C = 100 °C = 25 °C 0.1 0 0.1 0.2 0.3 0.4 0.5 0.6 0.7 0.8 Instantaneous Forward Voltage (V)

Fig. 3 - Typical Instantaneous Forward Characteristics

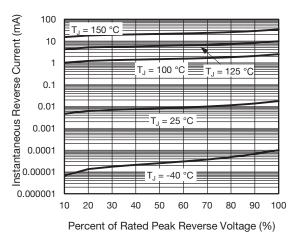


Fig. 4 - Typical Reverse Leakage Characteristics

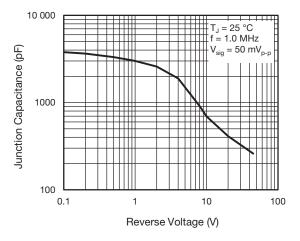


Fig. 5 - Typical Junction Capacitance

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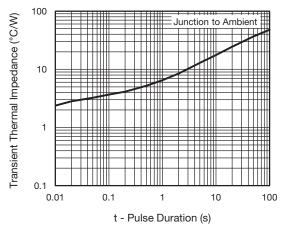


Fig. 6 - Typical Transient Thermal Impedance

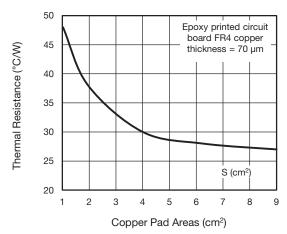
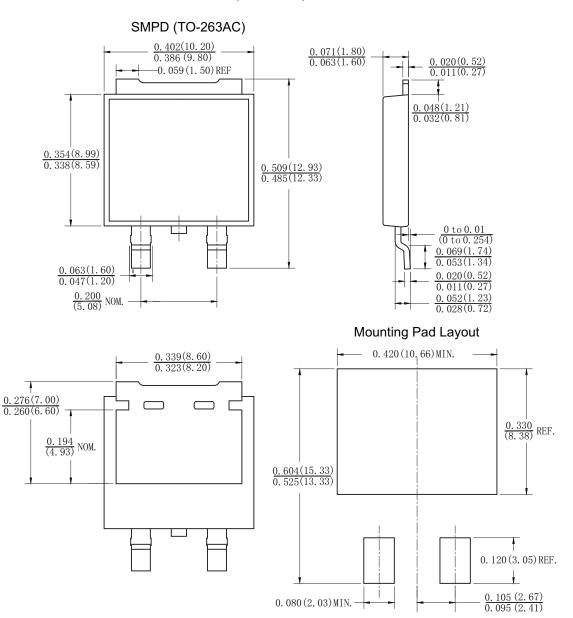


Fig. 7 - Thermal Resistance Junction-to-Ambient vs. Copper Pad Areas



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### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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